

HD74HC152

1-of-8-line Data Selector/Multiplexer

REJ03D0576-0200 (Previous ADE-205-450) Rev.2.00 Oct 11, 2005

Description

This data selector/multiplexer contains full-on-chip binary decoding to select the desired data source. The HD74HC152 selects one-of-eight data sources.

Features

- High Speed Operation: t_{pd} (Any D to W) = 17 ns typ ($C_L = 50 \text{ pF}$)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2 \text{ to } 6 \text{ V}$
- Low Input Current: 1 µA max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC152P	DILP-14 pin	PRDP0014AB-B (DP-14AV)	Ρ	
HD74HC152RPEL	SOP-14 pin (JEDEC)	PRSP0014DE-A (FP-14DNV)	RP	EL (2,500 pcs/reel)

Note: Please consult the sales office for the above package availability.

Function Table

	Select inputs		Output		Output		
С	В	Α	W	С	В	Α	W
L	L	Ļ	\overline{D}_0	Н	L	L	\overline{D}_4
L	L	Н	\overline{D}_1	Н	L	Н	\overline{D}_5
L	Н	L	\overline{D}_2	Н	Н	L	\overline{D}_6
L	н	H	\overline{D}_3	Н	Н	Н	\overline{D}_7

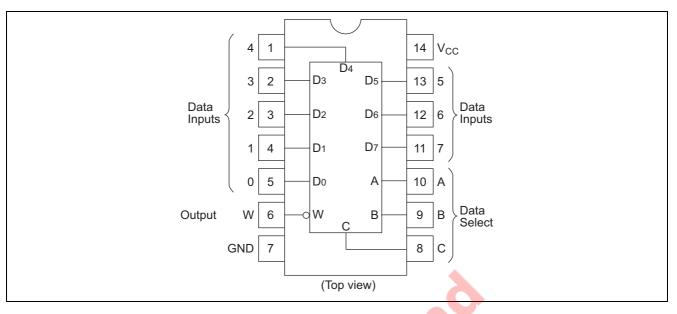
Note: D_0 to D_7 : the level of the D respective input

H: High level

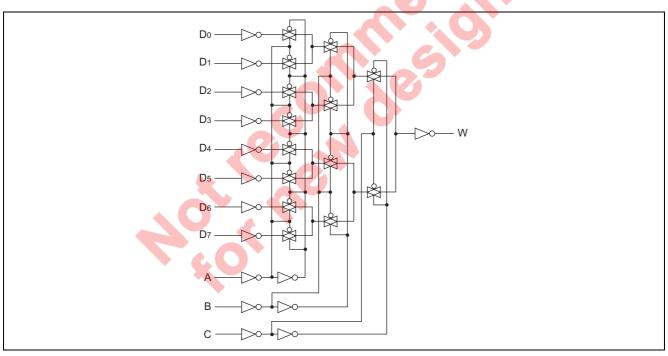
L: Low level



Pin Arrangement



Logic Diagram



Absolute Maximum Ratings

ltem	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to +7.0	V
Input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
Output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Output current	I _{OUT}	±25	mA
DC current drain per V _{CC} , GND	I _{CC} , I _{GND}	±50	mA
DC input diode current	l _{ik}	±20	mA
DC output diode current	Ι _{ΟΚ}	±20	mA
Power dissipation per package	PT	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions	
Supply voltage	Vcc	2 to 6	V		
Input / Output voltage	V _{IN} , V _{OUT}	0 to V _{CC}	V		
Operating temperature	Та	-40 to 85	O°		
		0 to 1000		V _{CC} = 2.0 V	
Input rise / fall time ^{*1}	t _r , t _f	0 to 500	ns	$V_{CC} = 4.5 V$	
		0 to 400		$V_{CC} = 6.0 V$	

Note: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.

Electrical Characteristics

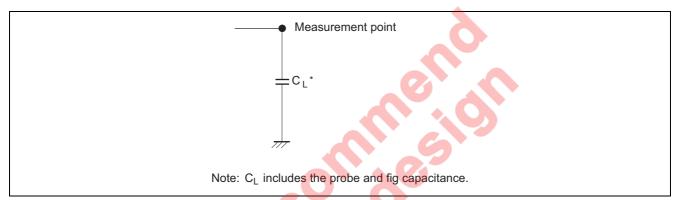
			Ta = 25°C Ta = -40 to+85°C							
ltem	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Cor	nditions
Input voltage	VIH	2.0	1.5			1.5	_	V		
		4.5	3.15	ſ	3	3.15	_			
		6.0	4.2	J	_	4.2	_			
	VIL	2.0			0.5	-	0.5	V		
		4.5		_	1.35	-	1.35			
		6.0		_	1.8	-	1.8			
Output voltage	V _{OH}	2.0	1.9	2.0	—	1.9	—	V	$Vin = V_{IH} \text{ or } V_{IL}$	I _{OH} = –20 µА
		4.5	4.4	4.5	—	4.4	—			
		6.0	5.9	6.0	—	5.9	—			
		4.5	4.18		_	4.13	_			$I_{OH} = -4 \text{ mA}$
		6.0	5.68		_	5.63	_			$I_{OH} = -5.2 \text{ mA}$
	V _{OL}	2.0		0.0	0.1		0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	I _{OL} = 20 μA
		4.5		0.0	0.1		0.1			
		6.0	—	0.0	0.1	_	0.1			
		4.5	—	—	0.26	_	0.33			$I_{OL} = 4 \text{ mA}$
		6.0	_	_	0.26	-	0.33			I _{OL} = 5.2 mA
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V _{CC} or GND	
Quiescent supply current	I _{CC}	6.0			4.0		40	μA	$Vin = V_{CC} \text{ or } GN$	ID, Iout = 0 μ A



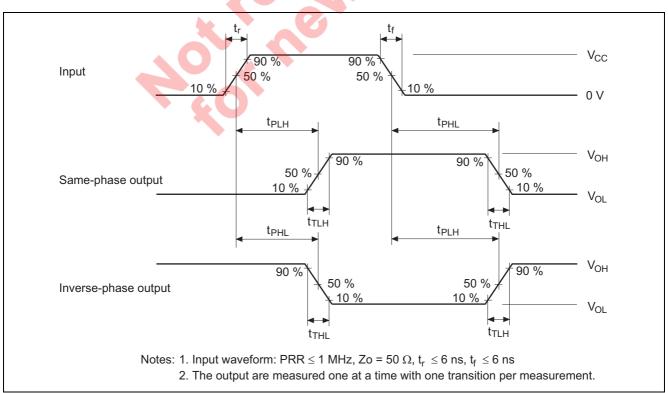
			Т	a = 25°	С	Ta = -40	to +85°C		
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t _{PLH} , t _{PHL}	2.0	_	_	160	—	200	ns	A, B or C to W
time		4.5		17	32	_	40		
		6.0		_	27	—	34		
	t _{PLH} , t _{PHL}	2.0			150	_	190	ns	Any D to W
		4.5		15	30	_	38		
		6.0			26	_	33		
Output rise/fall	t _{TLH} , t _{THL}	2.0			75	_	95	ns	
time		4.5		5	15	_	19		
		6.0	_	_	13	—	16		
Input capacitance	Cin	—		5	10	—	10	pF	

Switching Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

Test Circuit

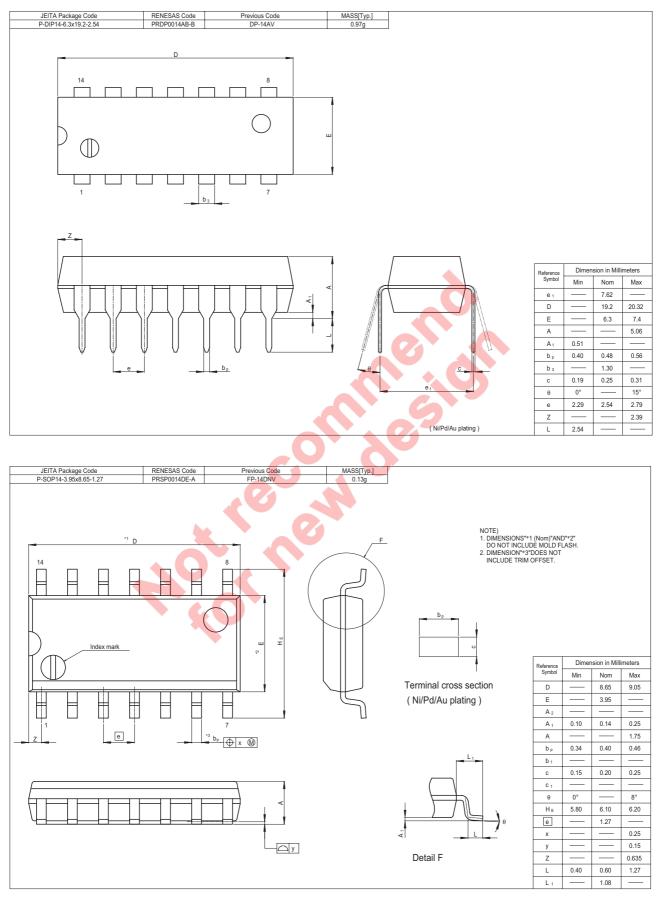


Waveforms





Package Dimensions





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